



### **MJE181G Information**



For Reference Only

Part Number MJE181G

Manufacturer ON Semiconductor

**Category** Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

**Description** TRANS NPN 60V 3A TO225AA

Package TO-225AA, TO-126-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# **MJE181G Specifications**

Manufacturer Part Number	MJE181G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-225AA, TO-126-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	3A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	1.7V @ 600mA, 3A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 100mA, 1V
Power - Max	1.5W
Frequency - Transition	50MHz
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-225AA, TO-126-3
Supplier Device Package	TO-225AA
	Report errors?

### **MJE181G Guarantees**



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

## **MJE181G Payment Methods**





















## **MJE181G Shipping Methods**













If you have any question about MJE181G, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com